

Operational Amplifier

Automotive Excellent EMI Immunity Input/Output Rail-to-Rail CMOS Operational Amplifier

BD87581YG-C BD87582YFVM-C BD87584YFV-C

General Description

BD87581YG-C, BD87582YFVM-C and BD87584YFV-C are input/output Rail-to-Rail CMOS operational amplifier. An operating voltage range is wide with 4 V to 14 V. This operational amplifier is the most suitable for automotive requirements such as sensor amplifier, engine control unit, electric power steering, anti-lock braking system and so on because it has features of high slew rate and low input bias current.

Furthermore, they have the advantage of EMI tolerance. It makes easier replacing with conventional products or simpler designing EMI.

Features

- EMARMOURTM Series
- AEC-Q100 Qualified(Note 1)
- Input/Output Rail-to-Rail
- Low Supply Current
- Wide Operating Supply Voltage Range
- High Open Loop Voltage Gain (Note 1) Grade 1

Applications

- Engine Control Unit
- Electric Power Steering (EPS)
- Anti-lock Braking System (ABS)
- Automotive Electronics

Key Specifications

■ Operating Supply Voltage Range
 Single Supply:
 Dual Supply:
 Uperating Temperature Range:
 Uperating Supply Voltage Range
 Uperating Supply Voltage Range
 Uperating Supply:
 Uperating

■ Input Offset Current: 1 pA (Typ)■ Input Bias Current: 1 pA (Typ)

Package

SSOP5 MSOP8 SSOP-B14 W (Typ) x D (Typ) x H (Max) 2.9 mm x 2.8 mm x 1.25 mm 2.9 mm x 4.0 mm x 0.9 mm 5.0 mm x 6.4 mm x 1.35 mm

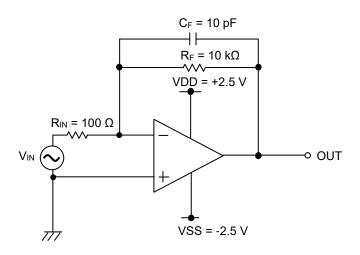
MSOP8





SSOP-B14

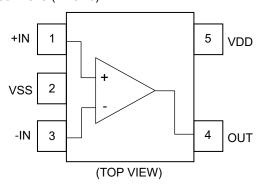
Typical Application Circuit



$$V_{OUT} = -\frac{R_F}{R_{IN}} V_{IN}$$

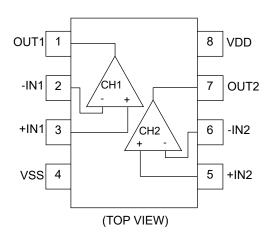
EMARMOUR™ is a trademark or a registered trademark of ROHM Co., Ltd.

Pin Description BD87581YG-C (SSOP5)



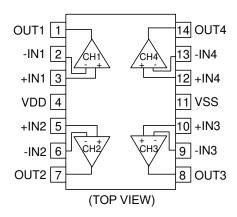
Pin No.	Pin Name
1	+IN
2	VSS
3	-IN
4	OUT
5	VDD

BD87582YFVM-C (MSOP8)



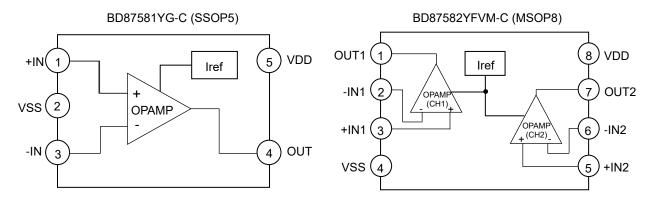
Pin No.	Pin Name				
1	OUT1				
2	-IN1				
3	+IN1				
4	VSS				
5	+IN2				
6	-IN2				
7	OUT2				
8	VDD				

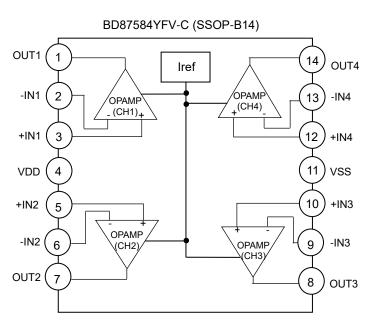
BD87584YFV-C (SSOP-B14)



Pin No.	Pin Name
1	OUT1
2	-IN1
3	+IN1
4	VDD
5	+IN2
6	-IN2
7	OUT2
8	OUT3
9	-IN3
10	+IN3
11	VSS
12	+IN4
13	-IN4
14	OUT4

Block Diagram





Description of Blocks

- 1. OPAMP:
 - This block is a Rail-to-Rail output operational amplifier with class-AB input / output circuit and differential input stage.
- 2. Iref:

This block supplies reference current which is needed to operate OPAMP block.

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{DD} -V _{SS}	15.5	V
Differential Input Voltage ^(Note 1)	VID	V _{DD} -V _{SS}	V
Common-mode Input Voltage Range	VICMR	(V _{SS} - 0.3) to (V _{DD} + 0.3)	V
Input Current	l _l	±10	mA
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

(Note 1) The differential input voltage indicates the voltage difference between inverting input and non-inverting input.

Thermal Resistance^(Note 2)

Parameter	Cymbol	Thermal Res	1.114	
Parameter	Symbol	1s ^(Note 4)	2s2p ^(Note 5)	- Unit
SSOP5				
Junction to Ambient	θја	376.5	185.4	°C/W
Junction to Top Characterization Parameter ^(Note 3)	Ψ_{JT}	40	30	°C/W
MSOP8				
Junction to Ambient	θЈΑ	284.1	135.4	°C/W
Junction to Top Characterization Parameter ^(Note 3)	Ψ_{JT}	21	11	°C/W
SSOP-B14				
Junction to Ambient	θЈА	159.6	92.8	°C/W
Junction to Top Characterization Parameter ^(Note 3)	Ψ_{JT}	13	9	°C/W

(Note 2) Based on JESD51-2A(Still-Air).

(Note 3) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 4) Using a PCB board based on JESD51-3.

(Note 5)	Using	а	PCB	board	based	0	n	JESD5	1-7	٠.

Layer Number of Measurement Board	Material	Board Size		
Single	FR-4	114.3 mm x 76.2 mm x	1.57 mmt	
Тор				
Copper Pattern	Thickness			
Footprints and Traces	70 µm			
Layer Number of Measurement Board	Material	Board Size		
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt		
Тор		2 Internal Layers		Bottom
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern

74.2 mm x 74.2 mm

35 µm

74.2 mm x 74.2 mm

Recommended Operating Conditions

Footprints and Traces

Parameter	Symbol	Min	Тур	Max	Unit
Operating Supply Voltage	V_{DD}	4.0 ±2.0	-	14.0 ±7.0	V
Operating Temperature	Topr	-40	+25	+125	Ŝ

70 µm

Thickness

70 µm

The input pin voltage is set to V_{SS} or more.

Function Explanation

1. EMARMOUR™

EMARMOUR™ is the brand name given to ROHM products developed by leveraging proprietary technologies covering layout, process, and circuit design to achieve ultra-high noise immunity that limits output voltage fluctuation to ±300 mV or less across the entire noise frequency band during noise evaluation testing under the international ISO11452-2 standard. This unprecedented noise immunity reduces design load while improving reliability by solving issues related to noise in the development of vehicle electrical systems.

BD073011G-C

Electrical Characteristics \circ BD87581YG-C (Unless otherwise specified V_{DD} = 5 V, V_{SS} = 0 V)

Davamatan	Symbol Temperature Limit			Unit	O a sa distina a a			
Parameter	Symbol	Range	Min	Тур	Max	Unit	Conditions	
1 10% 11/1	.,	25 °C	-	1	9	.,	V _{DD} = 4 V to 14 V	
Input Offset Voltage	V _{IO}	-40 °C to +125 °C	-	-	10	mV	Absolute value	
Input Offset Current	lıo	25 °C	-	1	-	pА	Absolute value	
Input Bias Current	I _B	25 °C	-	1	-	pА	Absolute value	
O		25 °C	-	2.3	3.2	A	R _L = ∞, G= 0 dB,	
Supply Current	I _{DD}	-40 °C to +125 °C	-	-	4.5	mA	+IN = 2.5 V	
0 () () () () ()	.,	25 °C	V _{DD} - 0.25	V _{DD} - 0.05	-	,,	D 4010	
Output Voltage High	Vон	-40 °C to +125 °C	V _{DD} - 0.3	-	-	V	$R_L = 10 \text{ k}\Omega$	
0.1.11/11/11		25 °C	-	0.03	0.25	.,	R _L = 10 kΩ	
Output Voltage Low	Vol	-40 °C to +125 °C	-	-	0.3	V		
	Av	25 °C	70	110	-	dB	D 4010	
Large Signal Voltage Gain		-40 °C to +125 °C	65	-	-		$R_L = 10 \text{ k}\Omega$	
Common-mode Input Voltage Range	V _{ICMR}	25 °C	0	-	5	V	-	
Common-mode Rejection	CMDD	25 °C	50	60	-	40		
Ratio	CMRR	-40 °C to +125 °C	45	-	-	– dB	-	
Power Supply Rejection	DCDD	25 °C	60	80	-	40		
Ratio	PSRR	-40 °C to +125 °C	55	-	-	– dB	-	
Out to the October 1		25 °C	2	3.5	-	A	V _{OUT} = V _{DD} - 0.4 V	
Output Source Current ^(Note 1)	Іон	-40 °C to +125 °C	1	-	-	mA	Absolute value	
O I I O I O (/Note 1)		25 °C	3.5	6	-		V _{OUT} = V _{SS} + 0.4 V	
Output Sink Current ^(Note 1)	loL	-40 °C to +125 °C	1.5	-	-	mA	Absolute value	
Slew Rate	SR	25 °C	-	3.5	-	V/µs	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF}$	
Gain Bandwidth Product	GBW	25 °C	-	4	-	MHz	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF},$ G = 40 dB	
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	f = 1 kHz, V _{OUT} = 1 Vrms	

⁽Note 1) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is short-circuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

Electrical Characteristics - continued

 \circ BD87582YFVM-C (Unless otherwise specified V_{DD} = 5 V, V_{SS} = 0 V)

Б	0 1 1	Temperature		Limit		Unit	Conditions	
Parameter	Symbol	Range	Min	Тур	Max			
1 10% 11/1	.,,	25 °C	-	1	9		V _{DD} = 4 V to 14 V	
Input Offset Voltage	Vio	-40 °C to +125 °C	-	-	10	mV	Absolute value	
Input Offset Current	lio	25 °C	-	1	-	рА	Absolute value	
Input Bias Current	I _B	25 °C	-	1	-	рА	Absolute value	
0 10 1		25 °C	-	5	7		$R_L = \infty$, $G = 0$ dB,	
Supply Current	I _{DD}	-40 °C to +125 °C	-	-	8	mA	+IN = 2.5 V	
	.,	25 °C	V _{DD} - 0.25	V _{DD} - 0.05	-	.,		
Output Voltage High	Vон	-40 °C to +125 °C	V _{DD} - 0.3	-	-	V	$R_L = 10 \text{ k}\Omega$	
•	.,	25 °C	-	0.03	0.25	.,		
Output Voltage Low	Vol	-40 °C to +125 °C	-	-	0.3	V	$R_L = 10 \text{ k}\Omega$	
		25 °C	70	110	-			
Large Signal Voltage Gain	Av	-40 °C to +125 °C	65	-	-	dB	$R_L = 10 \text{ k}\Omega$	
Common-mode Input Voltage Range	V _{ICMR}	25 °C	0	-	5	V	-	
Common-mode Rejection	OMBB	25 °C	50	60	-			
Ratio	CMRR	-40 °C to +125 °C	45	-	-	dB	-	
Power Supply Rejection	DODD	25 °C	60	80	-	-10		
Ratio	PSRR	-40 °C to +125 °C	55	-	-	dB	-	
0 1 10 0 1/Note 1)		25 °C	2	3.5	-		V _{OUT} = V _{DD} - 0.4 V	
Output Source Current ^(Note 1)	Іон	-40 °C to +125 °C	1	-	-	mA	Absolute value	
(/Note 1)		25 °C	3.5	6	-		V _{OUT} = V _{SS} + 0.4 V	
Output Sink Current ^(Note 1)	loL	-40 °C to +125 °C	1.5	-	-	mA	Absolute value	
Slew Rate	SR	25 °C	-	3.5	-	V/µs	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF}$	
Gain Bandwidth Product	GBW	25 °C	-	4	-	MHz	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF},$ G = 40 dB	
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	f = 1 kHz, V _{OUT} = 1 Vrms	
Channel Separation	CS	25 °C	-	100	-	dB	G = 40 dB, f = 1 kHz, V _{OUT} = 1 Vrms	

(Note 1) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is short-circuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

Electrical Characteristics - continued

 \circ BD87584YFV-C (Unless otherwise specified V_{DD} = 5 V, V_{SS} = 0 V)

Danamatan	Ols - l	Temperature		Limit		1.1	Conditions	
Parameter	Symbol	Range	Min	Тур	Max	Unit		
1 10% 11/1	.,,	25 °C	-	1	9		V _{DD} = 4 V to 14 V	
Input Offset Voltage	V _{IO}	-40 °C to +125 °C	-	-	10	mV	Absolute value	
Input Offset Current	lio	25 °C	-	1	-	рА	Absolute value	
Input Bias Current	I _B	25 °C	-	1	-	рА	Absolute value	
0 10 1		25 °C	-	10	14		$R_L = \infty$, $G = 0$ dB,	
Supply Current	I _{DD}	-40 °C to +125 °C	-	-	16	mA	+IN = 2.5 V	
	.,	25 °C	V _{DD} - 0.25	V _{DD} - 0.05	-	.,	D 4010	
Output Voltage High	Vон	-40 °C to +125 °C	V _{DD} - 0.3	-	-	V	$R_L = 10 \text{ k}\Omega$	
•	.,	25 °C	-	0.03	0.25	.,		
Output Voltage Low	Vol	-40 °C to +125 °C	-	-	0.3	V	$R_L = 10 \text{ k}\Omega$	
		25 °C	70	110	-			
Large Signal Voltage Gain	Av	-40 °C to +125 °C	65	-	-	dB	$R_L = 10 \text{ k}\Omega$	
Common-mode Input Voltage Range	V _{ICMR}	25 °C	0	-	5	V	-	
Common-mode Rejection	OMBB	25 °C	50	60	-			
Ratio	CMRR	-40 °C to +125 °C	45	-	-	dB	-	
Power Supply Rejection	DODD	25 °C	60	80	-	-10		
Ratio	PSRR	-40 °C to +125 °C	55	-	-	dB	-	
0 1 10 0 1/Note 1)		25 °C	2	3.5	-		V _{OUT} = V _{DD} - 0.4 V	
Output Source Current ^(Note 1)	Іон	-40 °C to +125 °C	1	-	-	mA	Absolute value	
(/Note 1)		25 °C	3.5	6	-		V _{OUT} = V _{SS} + 0.4 V	
Output Sink Current ^(Note 1)	loL	-40 °C to +125 °C	1.5	-	-	mA	Absolute value	
Slew Rate	SR	25 °C	-	3.5	-	V/µs	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF}$	
Gain Bandwidth Product	GBW	25 °C	-	4	-	MHz	$R_L = 10 \text{ k}\Omega, C_L = 10 \text{ pF},$ G = 40 dB	
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	f = 1 kHz, V _{OUT} = 1 Vrms	
Channel Separation	CS	25 °C	-	100	-	dB	G = 40 dB, f = 1 kHz, V _{OUT} = 1 Vrms	

(Note 1) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is short-circuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

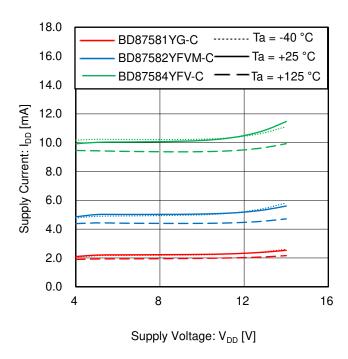


Figure 1. Supply Current vs Supply Voltage

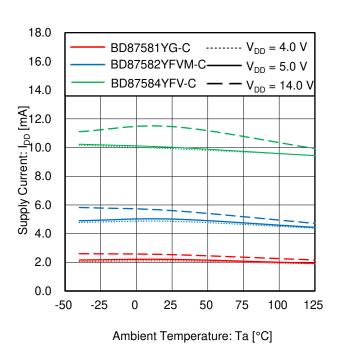


Figure 2. Supply Current vs Ambient Temperature

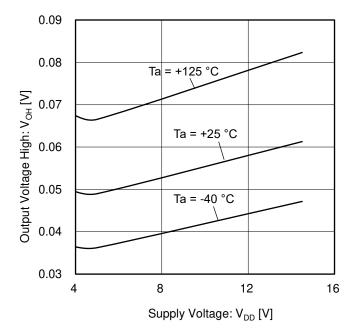


Figure 3. Output Voltage High vs Supply Voltage $(R_L = 10 \text{ k}\Omega, V_{OH} = V_{DD} - V_{OUT})$

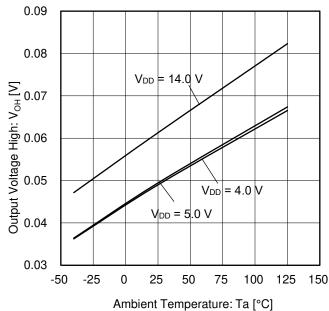


Figure 4. Output Voltage High vs Ambient Temperature ($R_L = 10 \text{ k}\Omega, \text{ V}_{OH} = \text{V}_{DD} - \text{V}_{OUT}$)

Typical Performance Curves - continued



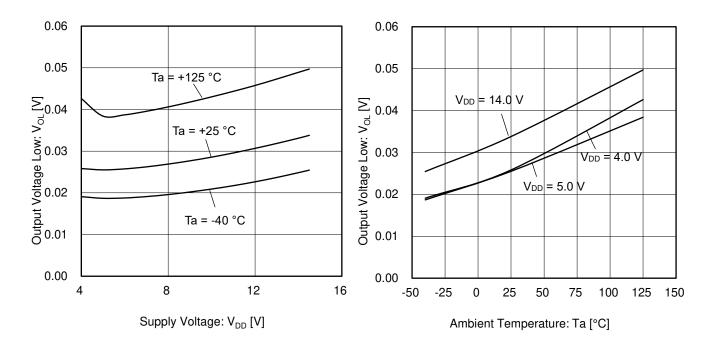


Figure 5. Output Voltage Low vs Supply Voltage $(R_L = 10 \text{ k}\Omega)$

Figure 6. Output Voltage Low vs Ambient Temperature $(R_L = 10 \text{ k}\Omega)$

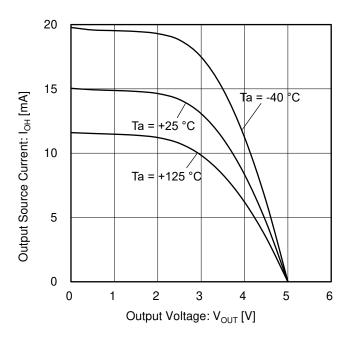


Figure 7. Output Source Current vs Output Voltage $(V_{DD} = 5 V)$

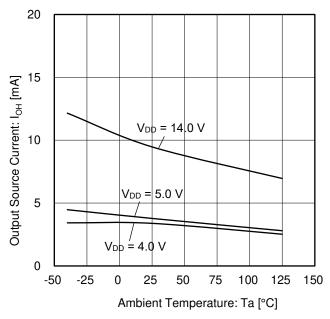


Figure 8. Output Source Current vs Ambient Temperature $(V_{OUT} = V_{DD} - 0.4 V)$

Typical Performance Curves - continued $V_{SS} = 0 V$

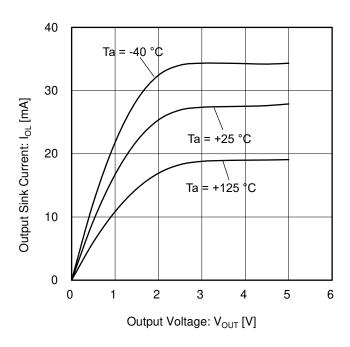


Figure 9. Output Sink Current vs Output Voltage $(V_{DD} = 5 V)$

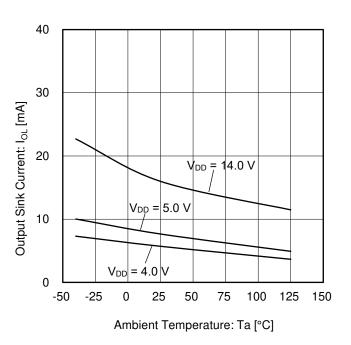


Figure 10. Output Sink Current vs Ambient Temperature $(V_{OUT} = V_{SS} + 0.4 V)$

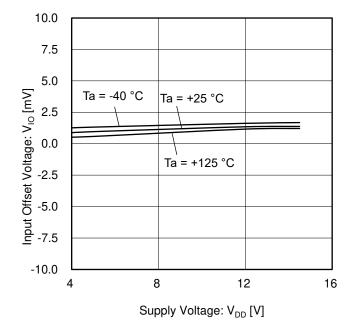


Figure 11. Input Offset Voltage vs Supply Voltage $(V_{ICM} = V_{DD}/2, E_K = -V_{DD}/2)$

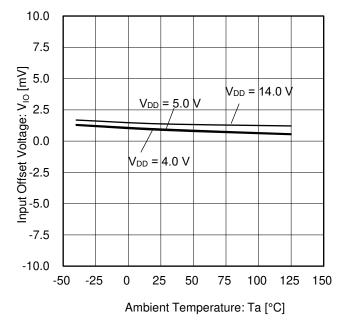
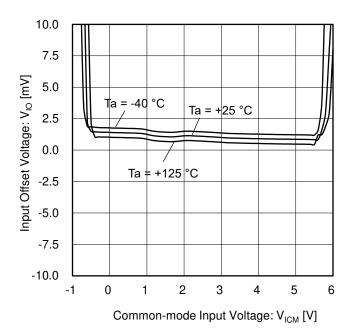


Figure 12. Input Offset Voltage vs Ambient Temperature $(V_{ICM} = V_{DD}/2, E_K = -V_{DD}/2)$



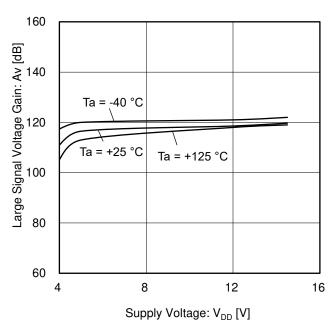
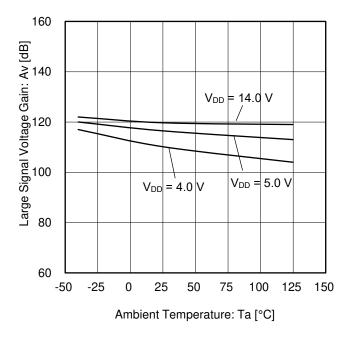


Figure 13. Input Offset Voltage Gain vs Common-mode Input Voltage (V_{DD} = 5 V)

Figure 14. Large Signal Voltage Gain vs Supply Voltage





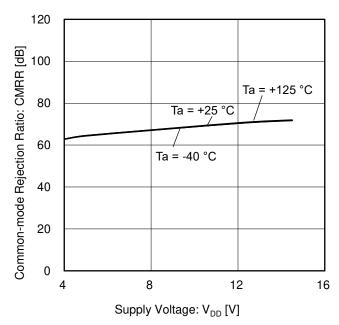
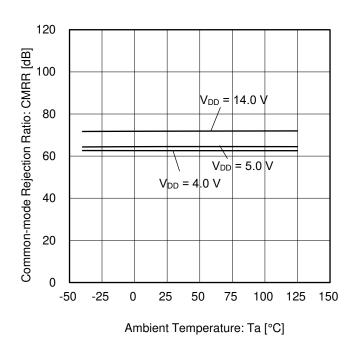


Figure 16. Common-mode Rejection Ratio vs Supply Voltage

9

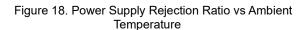
8

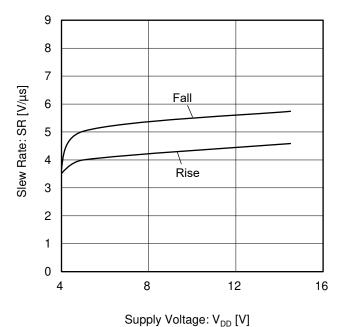
Typical Performance Curves - continued $V_{SS} = 0 V$



200 Power Supply Rejection Ratio: PSRR [dB] -50 -25 25 50 75 100 125 150 Ambient Temperature: Ta [°C]

Figure 17. Common-mode Rejection Ratio vs Ambient Temperature





7 Slew Rate: SR [V/µs] 6 Fall 5 4 Rise 3 2 1 0 -50 -25 0 25 50 75 100 125 150

Figure 19. Slew Rate vs Supply Voltage (Ta = 25 °C)

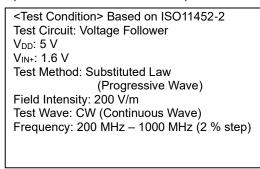
Figure 20. Slew Rate vs Ambient Temperature $(V_{DD} = 5 V)$

Ambient Temperature: Ta [°C]

Application Information

EMI Immunity

BD87581YG-C, BD87582YFVM-C and BD87584YFV-C have high tolerance for electromagnetic interference from the outside because they have EMI filter, and the EMI design is simple. They are most suitable to replace from conventional products. The data of the IC simple substance on ROHM board are as follows. The test condition is based on ISO11452-2.



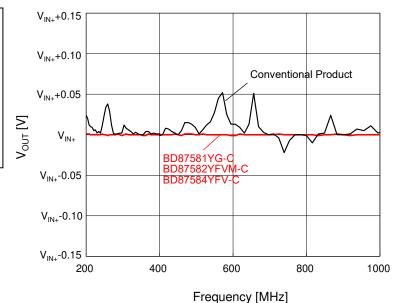


Figure 21. EMI Characteristics



Figure 22. EMI Evaluation Board (BD87581YG-C)

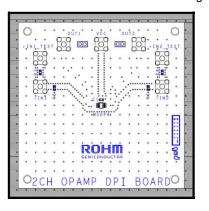


Figure 23. EMI Evaluation Board (BD87582YFVM-C)

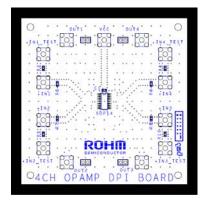


Figure 24. EMI Evaluation Board (BD87584YFV-C)

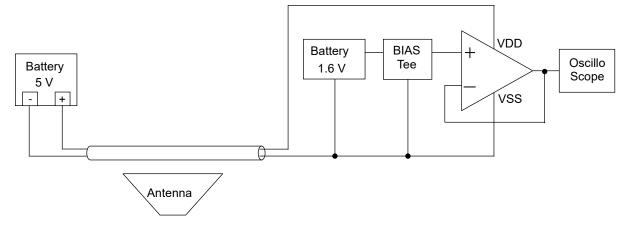


Figure 25. Measurement Circuit of EMI Evaluation

(Note) The above data is obtained using typical IC simple substance on ROHM board. These values are not guaranteed. Design and Evaluate in actual application before use.

Application Information - continued

1. Unused Circuits

When there are unused circuits, it is recommended that they are connected as in right figure, and set the non-inverting input pin to electric potential within the input common-mode voltage range (VICMR).

2. Input Voltage

Applying $V_{\rm DD}$ + 0.3 V to the input pin is possible without causing deterioration of the electrical characteristics or destruction, regardless of the supply voltage. However, this does not ensure circuit operation. Note that the circuit operates normally only when the input voltage is within the common-mode input voltage range of the electric characteristics.

3. Power Supply (single/dual)

The Op-Amp operates when the voltage is supplied between the VDD and VSS pin. Therefore, the single supply Op-Amp can be used as dual supply Op-Amp as well.

Connect to V_{ICM} V_{ICM} VSS

Figure 26. Example of application unused circuit processing

4. Output Capacitor

When the VDD pin is shorted to VSS (GND) electric potential in a state where electric charge is accumulated in the external capacitor that is connected to the output pin, the accumulated electric charge flow through parasitic elements or pin protection elements inside the circuit and discharges to the VDD pin. It may cause damage to the elements inside the circuit (thermal destruction). When using this IC as an application circuit which does not constitute a negative feedback circuit and does not occur the oscillation by an output capacitive load such as a voltage comparator, connect a capacitor of 0.1 µF or less to the output pin to prevent IC damage caused by the accumulation of electric charge as mentioned above.

5. Oscillation by Output Capacitor

Pay attention to the oscillation by capacitive load in designing an application which constitutes a negative feedback loop circuit with this IC.

6. Handling the IC

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations of the electrical characteristics due to the piezo resistance effects. Pay attention to defecting or bending the board.

Application Examples

Voltage Follower

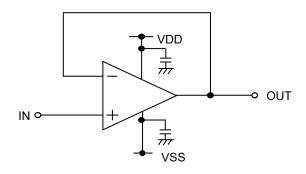


Figure 27. Voltage Follower Circuit

Using this circuit, the output voltage (V_{OUT}) is configured to be equal to the input voltage (V_{IN}) . This circuit also stabilizes the output voltage (V_{OUT}) due to high input impedance and low output impedance. Computation for output voltage (V_{OUT}) is shown below.

$$V_{OUT} = V_{IN}$$

Inverting Amplifier

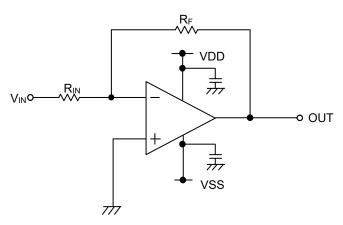


Figure 28. Inverting Amplifier Circuit

For inverting amplifier, input voltage (V_{IN}) is amplified by a voltage gain which depends on the ratio of R_{IN} and R_{F} , and then it outputs phase-inverted voltage. The output voltage is shown in the next expression.

$$V_{OUT} = -\frac{R_F}{R_{IN}} V_{IN}$$

This circuit has input impedance equal to R_{IN}.

○Non-inverting Amplifier

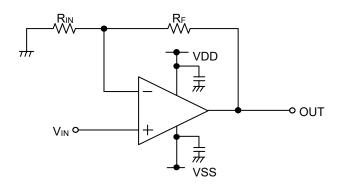


Figure 29. Non-inverting Amplifier Circuit

For non-inverting amplifier, input voltage (V_{IN}) is amplified by a voltage gain, which depends on the ratio of R_{IN} and R_F . The output voltage (V_{OUT}) is in-phase with the input voltage (V_{IN}) and is shown in the next expression.

$$V_{OUT} = \left(1 + \frac{R_F}{R_{IN}}\right) V_{IN}$$

Effectively, this circuit has high input impedance since its input side is the same as that of the operational amplifier.

I/O Equivalence Circuits BD87581YG-C

Pin No.	Pin Name	Pin Description	Equivalence Circuit
4	OUT	Output	5
1 3	+IN -IN	Input	1,3 Wd

OBD87582YFVM-C

Pin No.	Pin Name	Pin Description	Equivalence Circuit
1 7	OUT1 OUT2	Output	1,7
2 3 5 6	-IN1 +IN1 +IN2 -IN2	Input	2,3,5,6

I/O Equivalence Circuits - continued OBD87584YFV-C

Pin No.	Pin Name	Pin Description	Equivalence Circuit
1 7 8 14	OUT1 OUT2 OUT3 OUT4	Output	1, 7, 8, 14
2 3 5 6 9 10 12 13	-IN1 +IN1 +IN2 -IN2 -IN3 +IN3 +IN4 -IN4	Input	2, 3, 5, 6 9, 10, 12, 13

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes - continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

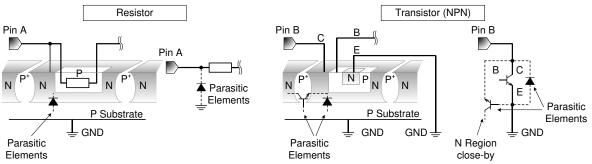


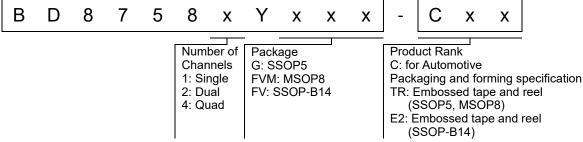
Figure 30. Example of Monolithic IC Structure

11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

BD87582YFVM-C

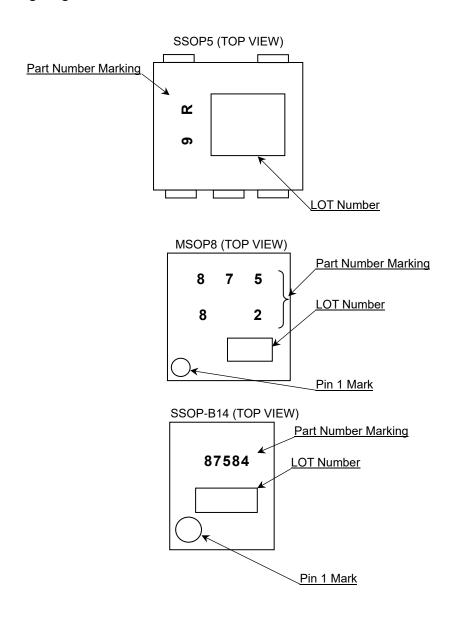
Ordering Information

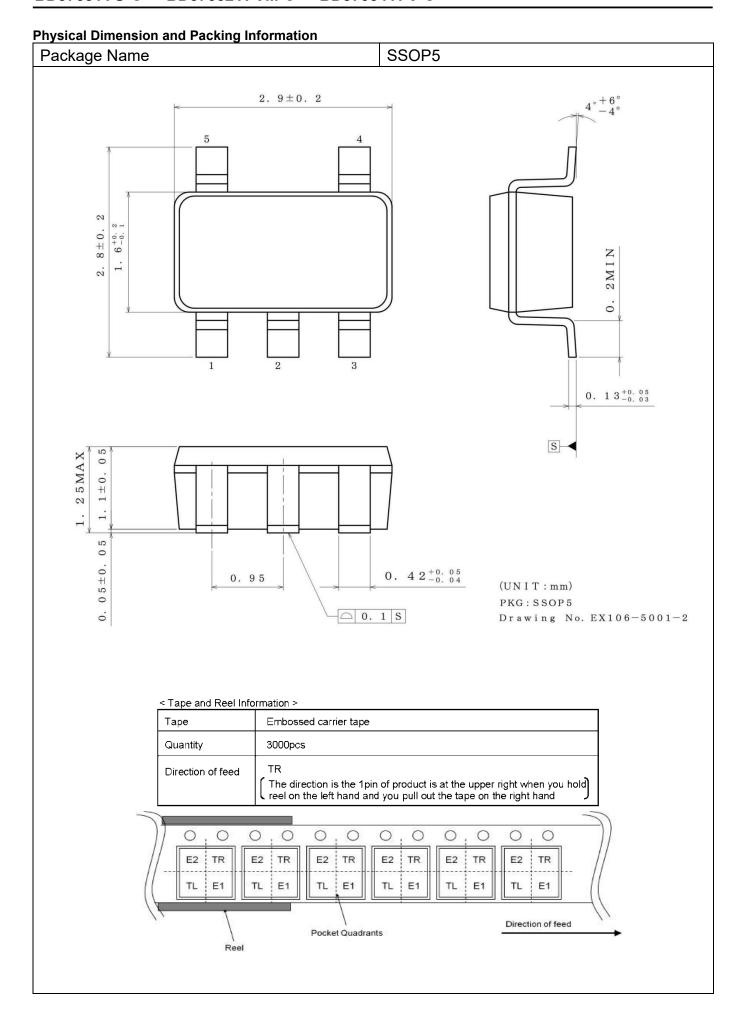


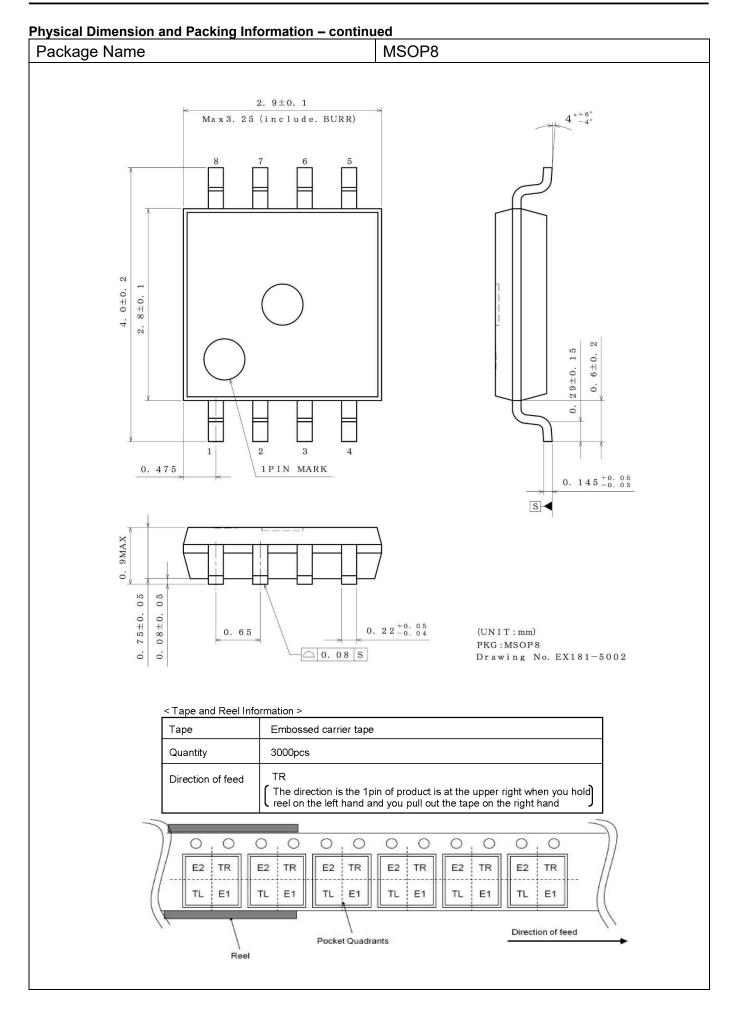
Lineup

Number of Channels	Package		Orderable Part Number
Single	SSOP5	Reel of 3000	BD87581YG-CTR
Dual	MSOP8	Reel of 3000	BD87582YFVM-CTR
Quad	SSOP-B14	Reel of 2500	BD87584YFV-CE2

Marking Diagram







Revi	Revision History			
	Date	Revision	Changes	
	15.Nov.2019	001	New Release	
	16.Jun.2020	002	Update Lineup (BD87582YFVM-C)	
	05.Feb.2021	003	Update Lineup (BD87584YFV-C)	
	01.Oct.2022	004	Modified title	

Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

1. 1010 1) modical Equipment Glacemoditor of the opening approach			
JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSⅢ
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

Other Precaution

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

Notice-PAA-E Rev.004

General Precaution

- 1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.

Notice – WE Rev.001